NSN 5962-01-013-8545

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View Online at https://aerobasegroup.com/nsn/5962-01-013-8545

Dl	Length:
BOOV	i enain.

Between 0.350 inches and 0.390 inches

Body Width:

Between 0.240 inches and 0.270 inches

Body Height:

Between 0.034 inches and 0.044 inches

Maximum Power Dissipation Rating:

1000.0 milliwatts

Operating Tempurature Range:

-20.0/+95.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and negative outputs and positive outputs and programmable and programmed and w/enable and w/storage

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Flat pack

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

-30.0 volts power source

Time Rating Per Chacteristic:

1000.00 nanoseconds propagation delay time, low to high level output and 1000.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Test Data Document:

13973-861553 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 flat leads

Shelf Life:

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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